



PHYSICAL CHARACTERISTICS	
Format	156mm×156mm±0.5mm
Diagonal	220mm±0.5mm
Thickness	190±20 μm
Front(-)	Blue reflecting coating(silicon nitride); 1.5mm busbars(silver);
Back(+)	surface field(Aluminum); 2.0mm wide soldering pads;

PHYSICAL CHARACTERISTICS	
Temperature coefficient of $I_{sc}(\alpha)$	0.055%/K
Temperature coefficient of $V_{oc}(\beta)$	-0.380%/K
Temperature coefficient of $P_{mpp}(\gamma)$	-0.459%/K

ELECTRICAL CHARACTERISTICS												
Efficiency	[%]	15.2	15.4	15.6	15.8	16.0	16.2	16.4	16.6	16.8	17.0	17.2
P_{mpp}	[W]	3.70	3.75	3.8	3.85	3.89	3.94	3.99	4.04	4.09	4.14	4.19
I_{sc}	[A]	7.99	8.02	8.05	8.09	8.13	8.18	8.22	8.26	8.31	8.37	8.44
V_{oc}	[V]	604.9	607.2	609.6	609.2	611.4	614.5	616.8	620.0	622.8	624.6	626.6
I_{mpp}	[A]	7.33	7.40	7.46	7.53	7.59	7.66	7.71	7.76	7.82	7.87	7.91
U_{mpp}	[mV]	504.8	506.8	509.4	511.3	512.5	514.4	517.5	520.6	523.0	526.0	529.7
FF	[%]	76.55	77.01	77.44	78.12	78.26	78.38	78.70	78.89	79.03	79.19	79.23

*The above data are presently measured average.

*Data under standard testing condition (STC):1000W/m²&500W/m²,AM1.5,25°C.

I-V CURVE	SPECTRAL RESPONSE	INTENSITY DEPENDENCE																		
		<table border="1"> <thead> <tr> <th>Intensity (W/m²)</th> <th>I_{sc} (A)</th> <th>V_{oc} (V)</th> </tr> </thead> <tbody> <tr> <td>1000</td> <td>1.0</td> <td>1.000</td> </tr> <tr> <td>900</td> <td>0.9</td> <td>0.995</td> </tr> <tr> <td>500</td> <td>0.5</td> <td>0.966</td> </tr> <tr> <td>300</td> <td>0.3</td> <td>0.940</td> </tr> <tr> <td>200</td> <td>0.2</td> <td>0.919</td> </tr> </tbody> </table>	Intensity (W/m ²)	I_{sc} (A)	V_{oc} (V)	1000	1.0	1.000	900	0.9	0.995	500	0.5	0.966	300	0.3	0.940	200	0.2	0.919
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※ratio of V_{oc} at reduced intensity to $V_{oc}(I_{sc})$ at 1000 W/m²